



# CMD240C4

## DC-22 GHz Distributed Amplifier

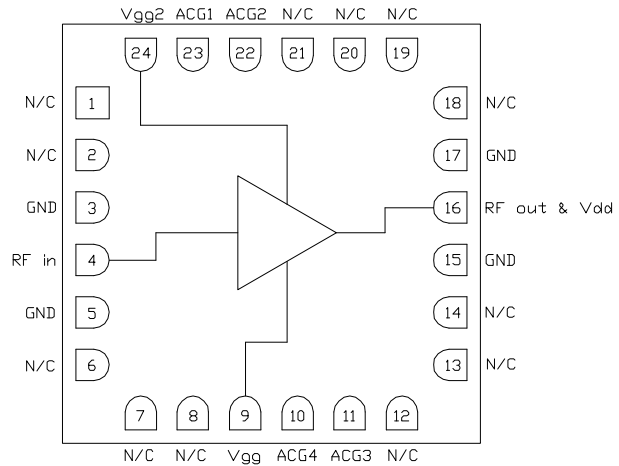
### Features

- ▶ Ultra wideband performance
- ▶ Low noise figure
- ▶ Low current consumption
- ▶ Excellent return losses
- ▶ Pb-free RoHs compliant 4x4 QFN package

### Description

The CMD240C4 is wideband GaAs MMIC distributed amplifier housed in a leadless 4x4 mm surface mount package. The amplifier operates from DC to 22 GHz and delivers greater than 15 dB of gain with a corresponding noise figure of 2 dB and output 1 dB compression point of +19 dBm at 10 GHz. The CMD240C4 is a 50 ohm matched design which eliminates the need for RF port matching.

### Functional Block Diagram



Note: Vgg2 is optional for gain control

### Electrical Performance - $V_{dd} = 5.0$ V, $I_{dd} = 80$ mA, $T_A = 25$ °C, $F = 10$ GHz

| Parameter          | Min     | Typ | Max | Units |
|--------------------|---------|-----|-----|-------|
| Frequency Range    | DC - 22 |     |     | GHz   |
| Gain               |         | 15  |     | dB    |
| Noise Figure       |         | 2   |     | dB    |
| Input Return Loss  |         | 15  |     | dB    |
| Output Return Loss |         | 13  |     | dB    |
| Output P1dB        |         | 19  |     | dBm   |
| Output IP3         |         | 27  |     | dBm   |
| Output IP2         |         | 27  |     | dBm   |
| Supply Current     |         | 80  |     | mA    |

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### Specifications

#### Absolute Maximum Ratings

| Parameter                            | Rating        |
|--------------------------------------|---------------|
| Drain Voltage, V <sub>dd</sub>       | 4.5 to 10 V   |
| Gate Voltage, V <sub>gg</sub>        | -2.5 to 0 V   |
| RF Input Power                       | +20 dBm       |
| Channel Temperature, T <sub>ch</sub> | 150 °C        |
| Power Dissipation, P <sub>diss</sub> | 1.7 W         |
| Thermal Resistance, $\Theta_{JC}$    | 38 °C/W       |
| Operating Temperature                | -40 to 85 °C  |
| Storage Temperature                  | -55 to 150 °C |

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

#### Recommended Operating Conditions

| Parameter       | Min | Typ  | Max | Units |
|-----------------|-----|------|-----|-------|
| V <sub>dd</sub> | 5.0 | 5.0  | 8.0 | V     |
| I <sub>dd</sub> |     | 80   |     | mA    |
| V <sub>gg</sub> |     | -0.6 |     | V     |

Electrical performance is measured at specific test conditions. Electrical specifications are not guaranteed over all recommended operating conditions.

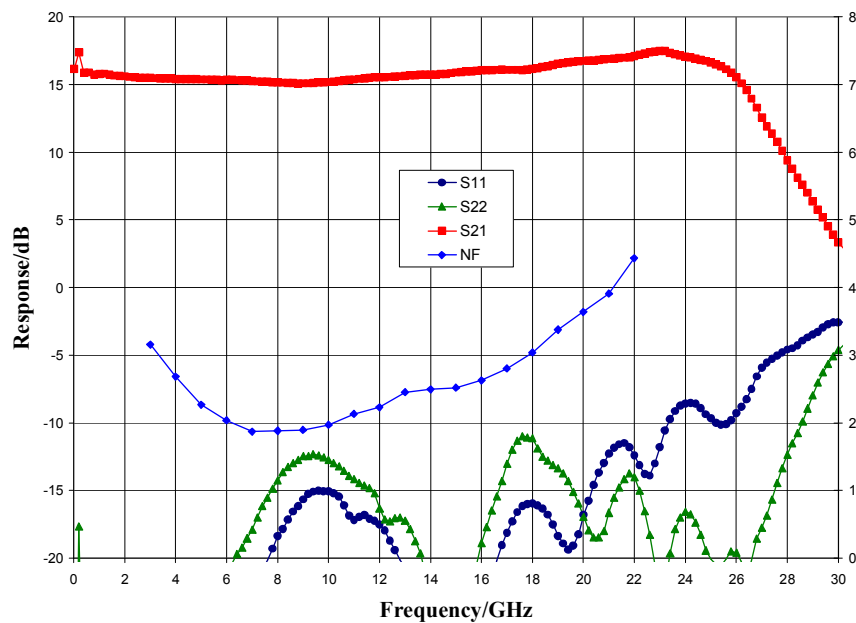
#### Electrical Specifications, V<sub>dd</sub> = 5.0 V, I<sub>dd</sub> = 80 mA, T<sub>A</sub> = 25 °C

| Parameter                            | Min     | Typ  | Max | Min    | Typ  | Max | Units |
|--------------------------------------|---------|------|-----|--------|------|-----|-------|
| Frequency Range                      | DC - 22 |      |     | 6 - 18 |      |     | GHz   |
| Gain                                 | 12      | 15   |     | 12     | 16   |     | dB    |
| Noise Figure                         |         | 2.5  |     |        | 2.2  |     | dB    |
| Input Return Loss                    |         | 15   |     |        | 15   |     | dB    |
| Output Return Loss                   |         | 13   |     |        | 13   |     | dB    |
| Output P1dB                          | 13      | 19   |     | 15     | 19   |     | dBm   |
| Output IP3                           |         | 26   |     |        | 26   |     | dBm   |
| Output IP2                           |         | 30   |     |        | 30   |     | dBm   |
| Supply Current                       | 55      | 80   | 105 | 55     | 80   | 105 | mA    |
| Gain Temperature Coefficient         |         | 0.01 |     |        | 0.01 |     | dB/°C |
| Noise Figure Temperature Coefficient |         | 0.01 |     |        | 0.01 |     | dB/°C |

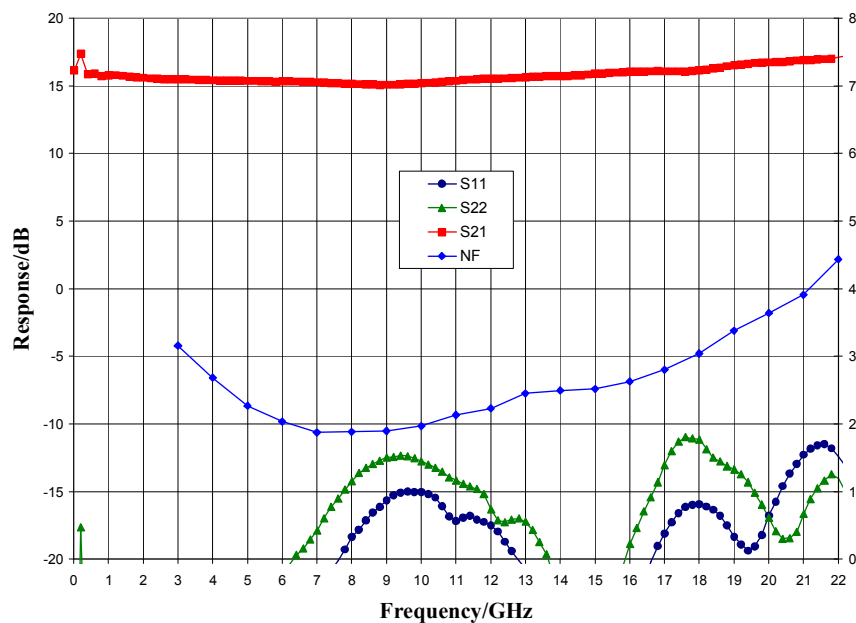
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### Typical Performance

**Broadband Performance,  $V_{dd} = 5\text{ V}$ ,  $I_{dd} = 80\text{ mA}$ ,  $T_A = 25\text{ }^{\circ}\text{C}$**



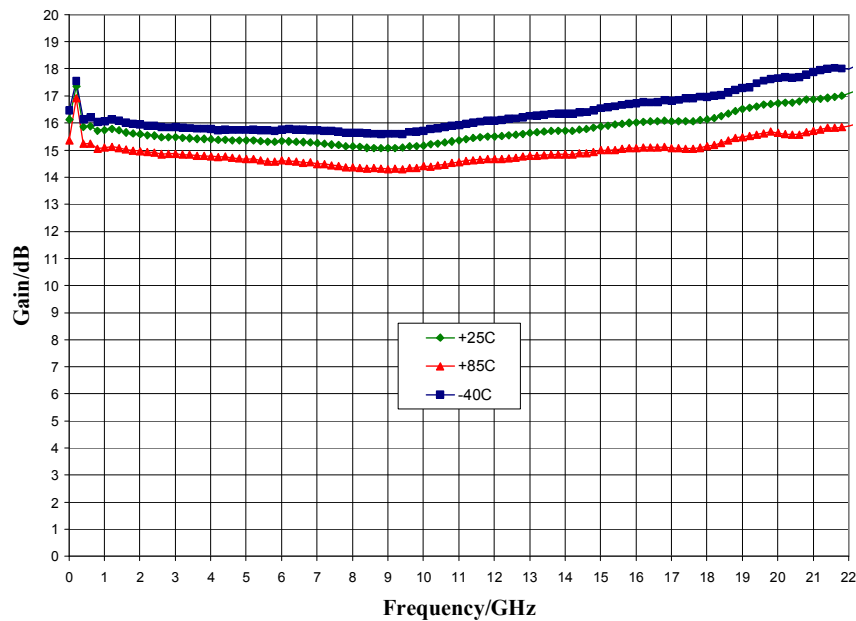
**Narrow-band Performance,  $V_{dd} = 5\text{ V}$ ,  $I_{dd} = 80\text{ mA}$ ,  $T_A = 25\text{ }^{\circ}\text{C}$**



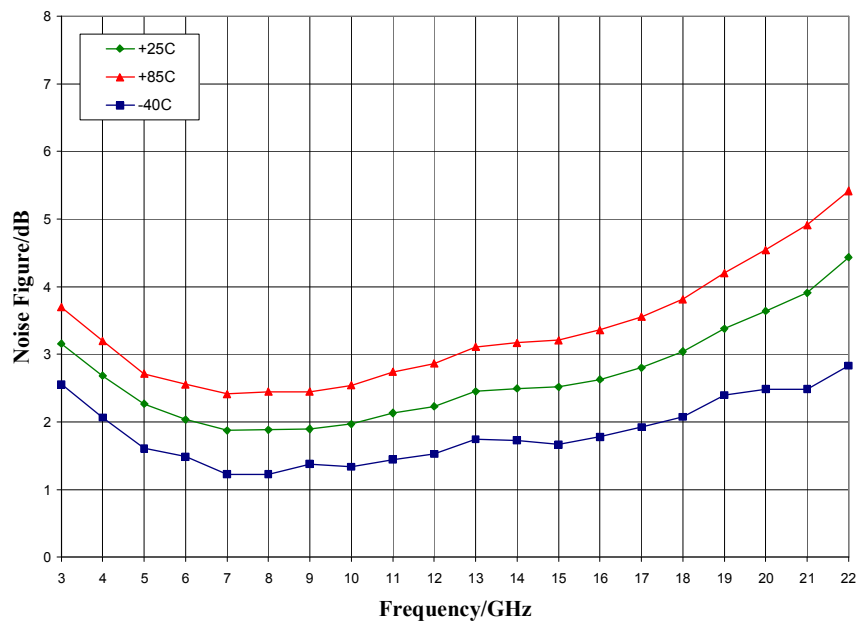
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### Typical Performance

**Gain vs. Temperature,  $V_{dd} = 5\text{ V}$**

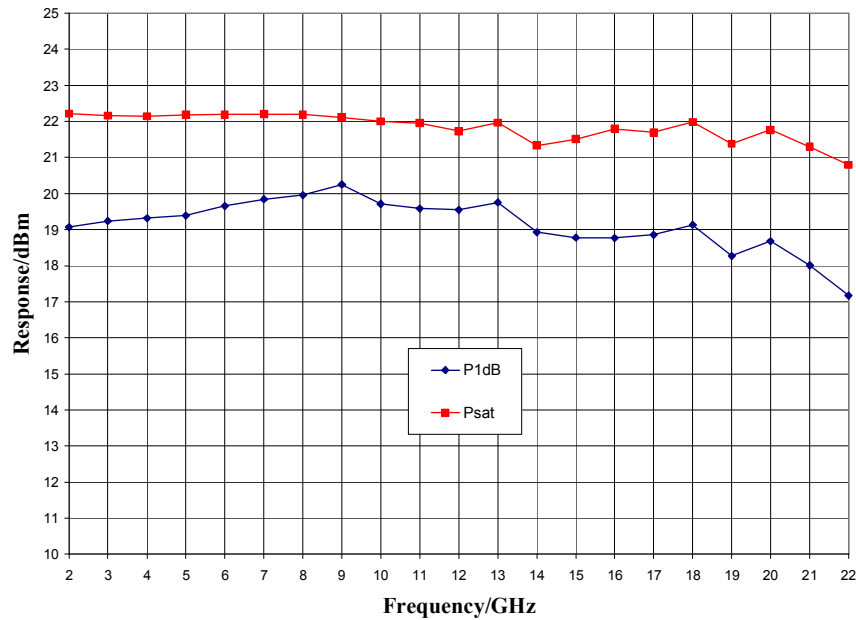


**Noise Figure vs. Temperature,  $V_{dd} = 5\text{ V}$**

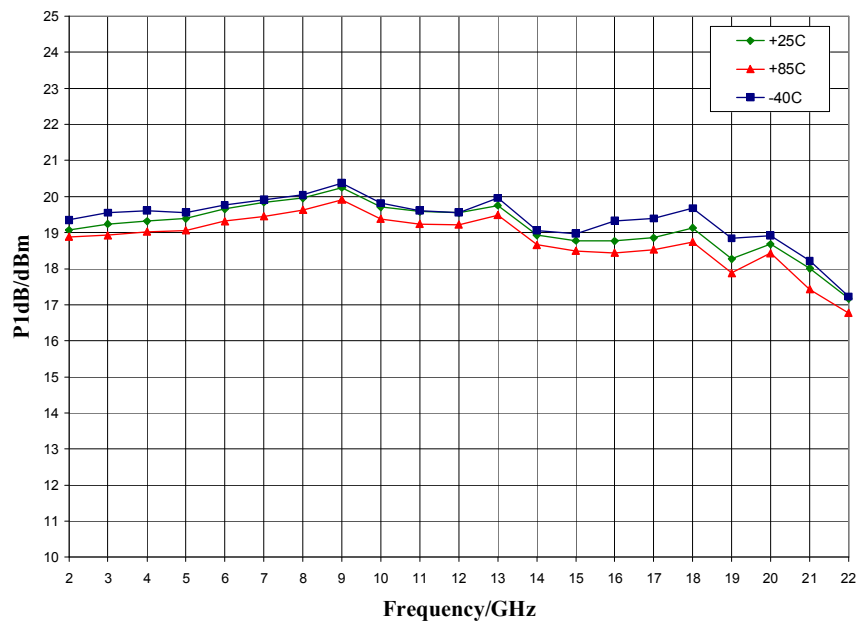


### Typical Performance

Output Power,  $V_{dd} = 5\text{ V}$ ,  $T_A = 25\text{ }^{\circ}\text{C}$



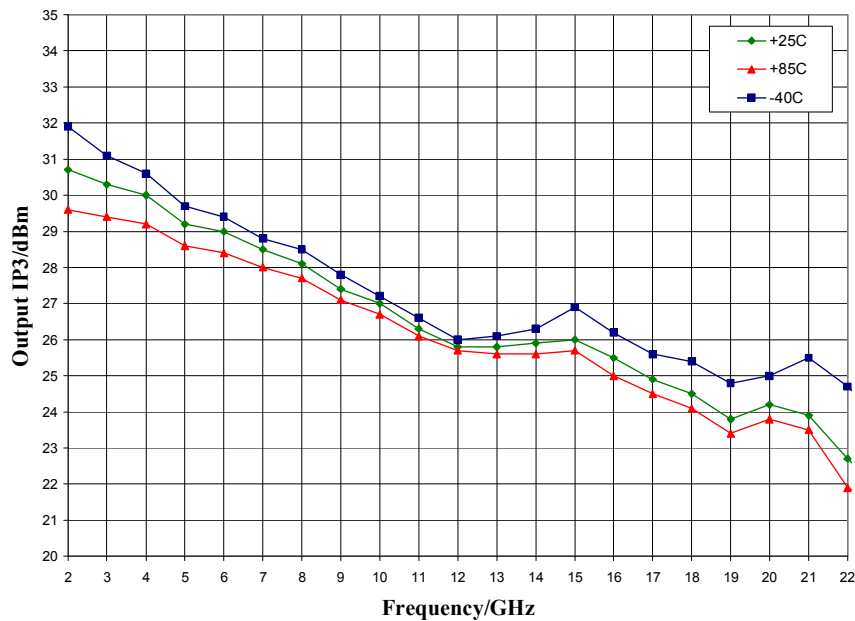
P1dB vs. Temperature,  $V_{dd} = 5\text{ V}$



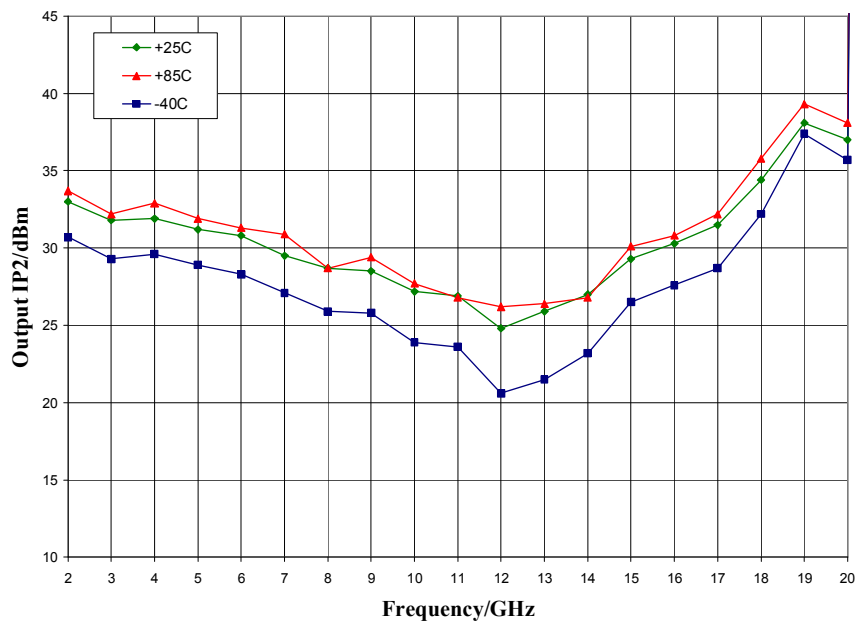
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### Typical Performance

Output IP3 vs. Temperature,  $V_{dd} = 5\text{ V}$



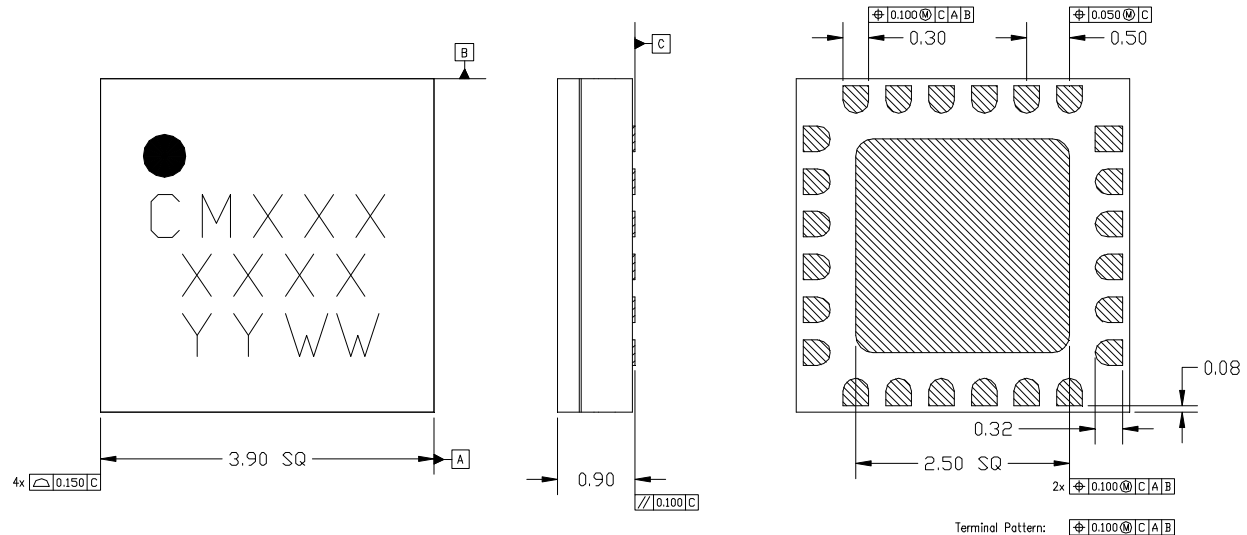
Output IP2,  $V_{dd} = 5\text{ V}$ ,  $T_A = 25\text{ °C}$



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### Mechanical Information

#### Package Information and Dimensions



- NOTES:
1. ALL DIMENSIONS SHOWN IN mm.
  2. MATERIAL: BLACK ALUMINA
  3. LEAD FINISH:
    - 3.1. Ni: 8.89um MAX, 1.27um MIN
    - 3.2. Pd: 0.17um MAX, 0.07um MIN
    - 3.3. Au: 0.254um MAX, 0.03um MIN
  4. MARKING
    - 4.1. LINE 1: PART NUMBER  
4.1.1. EXAMPLE: CMD191C4 SHALL BE MARKED AS CM191
    - 4.2. LINE 2: LOT NUMBER
    - 4.3. LINE 3: DATE CODE - LAST 2 DIGITS OF THE YEAR OF MANUFACTURE FOLLOWED BY A 2 DIGIT WEEK CODE
  5. ALTERNATE PIN #1 IDENTIFIER IS A SINGLE SQUARE PAD
  6. ALTERNATE DIE PADDLE MAY HAVE CHAMFERED CORNERS

#### Recommended PCB Land Pattern

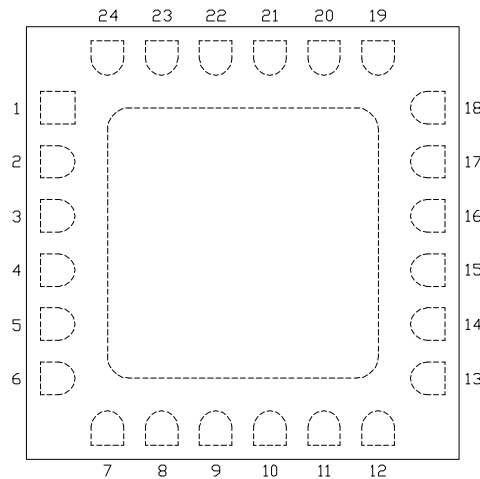
Custom MMIC Design Services recommends that the user develop the land pattern that will provide the best design for proper solder reflow and device attach for their specific application. Please review Custom MMIC Application Note AN 105 for a recommended land pattern approach.

#### Recommended Solder Reflow Profile

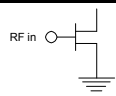
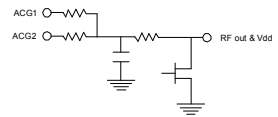
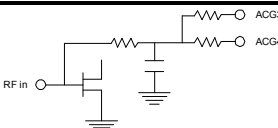
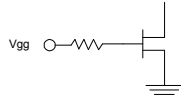
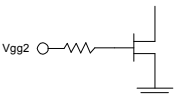
Custom MMIC Design Services recommends screen printing with belt furnace reflow to ensure proper solder reflow and device attach. Please review Custom MMIC Application Note AN 102 for a recommended solder reflow profile.

### Pin Description

### Pin Diagram



### Functional Description

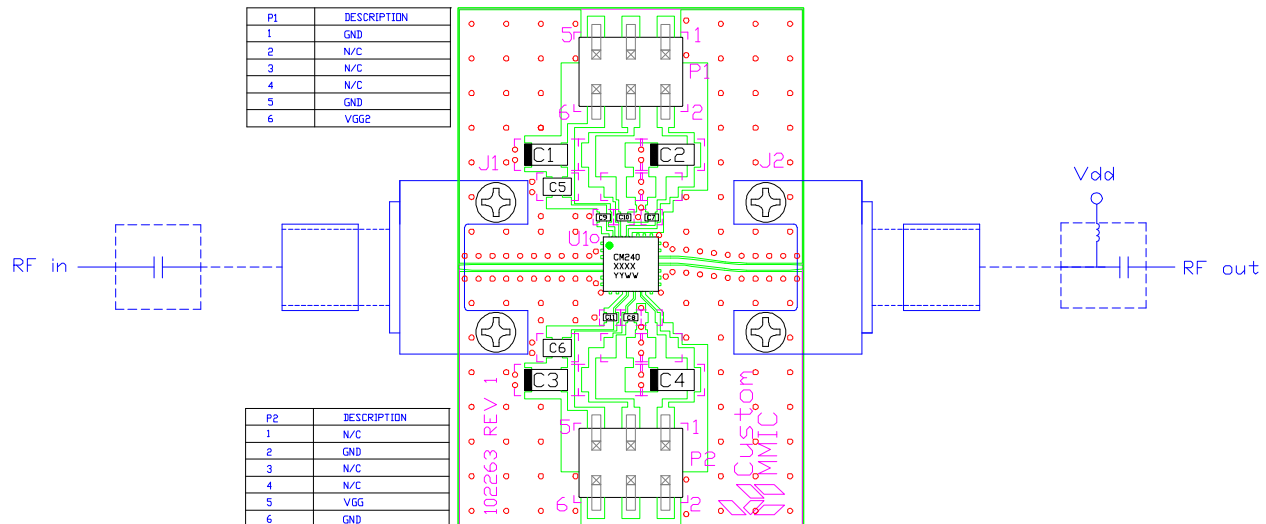
| Pin                         | Function     | Description                                                                                                           | Schematic                                                                             |
|-----------------------------|--------------|-----------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|
| 1, 2, 6-8, 12-14, 18-21     | N/C          | No connection required. These pins may be connected to RF/DC ground                                                   |                                                                                       |
| 4                           | RF in        | 50 ohm matched input                                                                                                  |  |
| 22, 23                      | ACG2, 1      | Low frequency termination. Attach bypass capacitors per application circuit                                           |  |
| 16                          | RF out & Vdd | Power supply voltage and 50 ohm matched output                                                                        |                                                                                       |
| 10, 11                      | ACG4, 3      | Low frequency termination. Attach bypass capacitors per application circuit                                           |  |
| 9                           | Vgg          | Power supply voltage<br>Decoupling and bypass caps required                                                           |  |
| 24                          | Vgg2         | Optional supply voltage for gain control.<br>Decoupling and bypass caps required.<br>Pin must be left open if unused. |  |
| 3, 5, 15, 17 and die paddle | Ground       | Connect to RF / DC ground                                                                                             |  |

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### Applications Information

### Evaluation Board



### Bill of Material

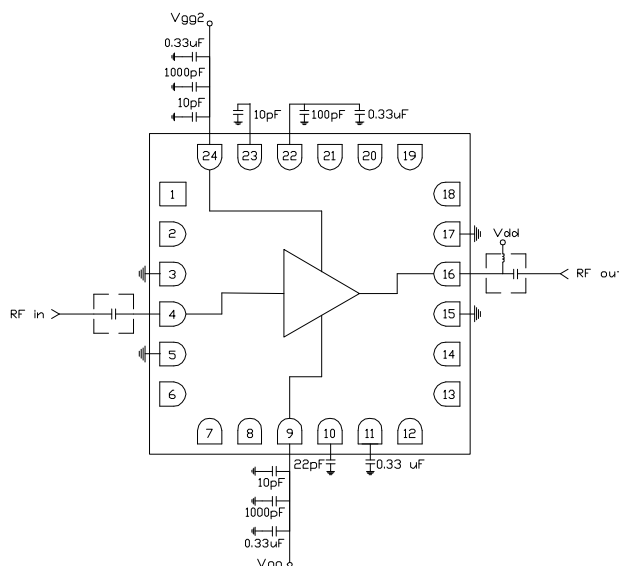
| Designator | Value        | Description               |
|------------|--------------|---------------------------|
| J1, J2     |              | SMA End Launch Connector  |
| P1, P2     |              | 6 Pin DC Header           |
| C1-C4      | 0.33 $\mu$ F | Capacitor, Tantalum       |
| C5, C6     | 1000 pF      | Capacitor, 0603           |
| C7         | 100 pF       | Capacitor, 0402           |
| C8         | 22 pF        | Capacitor, 0402           |
| C9-C11     | 10 pF        | Capacitor, 0402           |
| U1         |              | CMD240C4 Driver Amplifier |
| PCB        |              | 102263 Evaluation PCB     |

Please note, all information contained in this data sheet is subject to change without notice.

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### Applications Information

#### Application Circuit



Note: Drain voltage ( $V_{dd}$ ) must be applied through a broadband bias tee or external bias network. External DC block is required on RF input.

#### Biasing and Operation

The CMD240C4 is biased with a positive drain supply and negative gate supply. Performance is optimized when the drain voltage is set to +5.0 V. The nominal gate voltage is -0.6 V.

Turn ON procedure:

1. Apply gate voltage  $V_{gg}$  and set to -2 V
2. Apply drain voltage  $V_{dd}$  and set to +5 V
3. Increase  $V_{gg}$  (less negative) to achieve a drain current of 80 mA

Turn OFF procedure:

1. Turn off drain voltage  $V_{dd}$
2. Turn off gate voltage  $V_{gg}$

RF power can be applied at any time.

**GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.**

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